

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifier



DO-214AA (SMB)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	2.0 A			
V _{RRM}	100 V, 150 V, 200 V			
I _{FSM}	50 A			
t _{rr}	20 ns			
V _F at I _F = 2.0 A	0.76 V			
T _J max.	150 °C			

FEATURES

· Oxide planar chip junction



- Ultrafast recovery time
- · Low forward voltage, low power losses
- High forward surge capability

RoHS

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: DO-214AA (SMB)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	U2B	U2C	U2D	UNIT
Device marking code		U2B	U2C	U2D	
Maximum repetitive peak reverse voltage	V _{RRM}	100	150	200	V
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	2.0			Α
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	50			А
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150			°C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage (1)	I _F = 2 A	T _A = 25 °C T _A = 100 °C	V_{F}	0.86 0.76	0.90 0.83	V
Reverse current (2)	rated V _R	T _A = 25 °C T _A = 100 °C	I _R	- 180	10 350	μА
Reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$	T _A = 25 °C	t _{rr}	-	20	ns
	$I_F = 2.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$	T _A = 25 °C T _A = 100 °C	t _{rr}	27 35	-	ns
Storage charge	$I_F = 2.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$	T _A = 25 °C T _A = 100 °C	Q _{rr}	9 19		nC
Typical junction capacitance	4.0 V, 1 MHz		CJ	16	-	pF

Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	U2B	U2C	U2D	UNIT
Typical thermal resistance (1)	$R_{ hetaJA} \ R_{ hetaJM}$	105 18		°C/W	

Note:

(1) Free air, mounted on recommended copper pad area. Thermal resistance $R\theta_{JA}$ - junction to ambient, $R\theta_{JM}$ - junction to mount.

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
U2D-E3/52T	0.099	52T	750	7" diameter plastic tape and reel	
U2D-E3/5BT	0.099	5BT	3200	13" diameter plastic tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

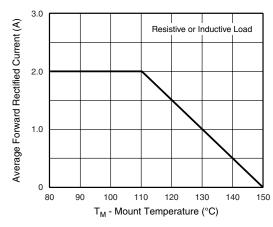


Figure 1. Maximum Forward Current Derating Curve

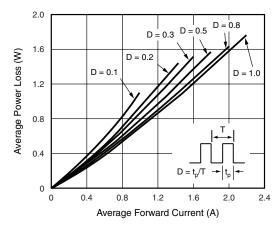


Figure 2. Forward Power Loss Characteristics



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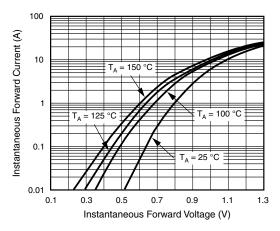


Figure 3. Typical Instantaneous Forward Characteristics

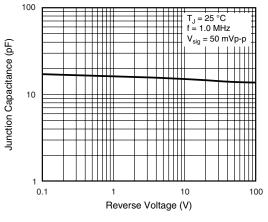


Figure 5. Typical Junction Capacitance

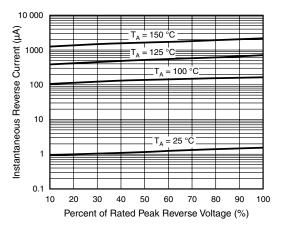


Figure 4. Typical Reverse Characteristics

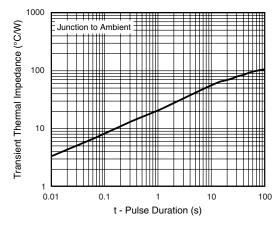
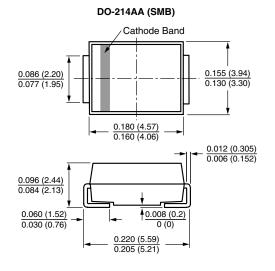
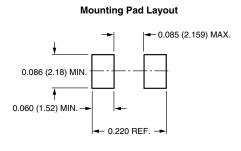


Figure 6. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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